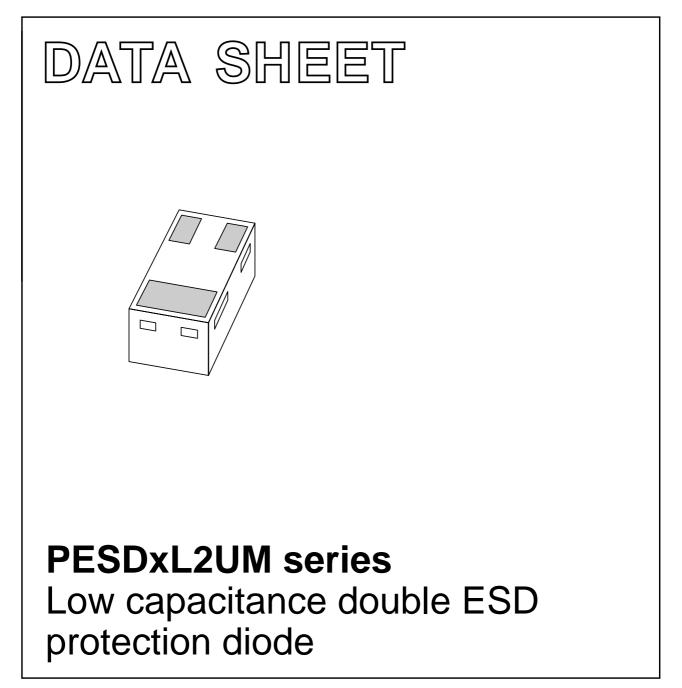
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 2003 Aug 05 2005 May 23



PESDxL2UM series

FEATURES

- Uni-directional ESD protection of two lines or bi-directional ESD protection of one line
- Reverse standoff voltage 3.3 and 5 V
- Low diode capacitance
- Ultra low leakage current
- Leadless ultra small SOT883 surface mount package (1 \times 0.6 \times 0.5 mm)
- Board space 1.17 mm² (approx. 10% of SOT23)
- ESD protection >15 kV
- IEC 61000-4-2; level 4 (ESD); 15 kV (air) or 8 kV (contact).

APPLICATIONS

- Cellular handsets and accessories
- Portable electronics
- Computers and peripherals
- Communication systems
- Audio and video equipment.

MARKING

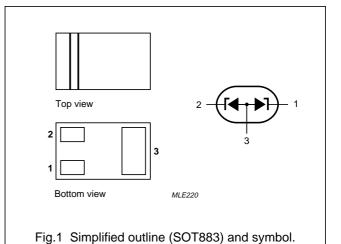
TYPE NUMBER	MARKING CODE
PESD3V3L2UM	F2
PESD5V0L2UM	F1

DESCRIPTION

Low capacitance ESD protection diode in a three pad SOT883 leadless ultra small plastic package designed to protect up to two transmission or data lines from ElectroStatic Discharge (ESD) damage.

PINNING

PIN	DESCRIPTION	
1	cathode 1	
2	cathode 2	
3	common anode	



PESDxL2UM series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER CONDITIONS		MIN.	MAX.	UNIT	
Per diode						
I _{pp}	peak pulse current 8/20 μs pulse; notes 1, 2 and 3					
	PESD3V3L2UM		-	3	А	
	PESD5V0L2UM		_	2.5	А	
P _{pp}	peak pulse power	8/20 μs pulse; notes 1, 2 and 3	-	30	W	
I _{FSM}	non-repetitive peak forward current	t _p = 1 ms; square pulse	-	3.5	A	
I _{ZSM}	non-repetitive peak reverse current	t _p = 1 ms; square pulse				
	PESD3V3L2UM		-	0.9	А	
	PESD5V0L2UM		-	0.8	А	
P _{tot}	total power dissipation	$T_{amb} = 25 \text{ °C}; \text{ note } 4$ –		250	mW	
P _{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 1 \text{ ms}; \text{ square pulse}; \text{ see Fig.4} - 6$		6	W	
T _{stg}	storage temperature	-6		+150	°C	
Tj	junction temperature	- 1		150	°C	
ESD	electrostatic discharge	IEC 61000-4-2 (contact discharge)	15	_	kV	
		HBM MIL-Std 883	10	_	kV	

Notes

- 1. Non-repetitive current pulse 8/20 µs exponential decay waveform; see Fig.5.
- 2. Pins 1 and 3 or 2 and 3.
- 3. Pins 1 and 2.
- 4. Device mounted on standard printed-circuit board.

ESD standards compliance

IEC 61000-4-2, level 4 (ESD)	>15 kV (air); >8 kV (contact)
HBM MIL-Std 883, class 3	>4 kV

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	all diodes loaded; note 1	500	K/W
		one diode loaded; note 2	290	K/W

Notes

- 1. Refer to SOT883 standard mounting conditions (footprint), FR4 with 60 μm copper strip line.
- 2. FR4 single-sided copper 1 cm².

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ELECTRICAL CHARACTERISTICS

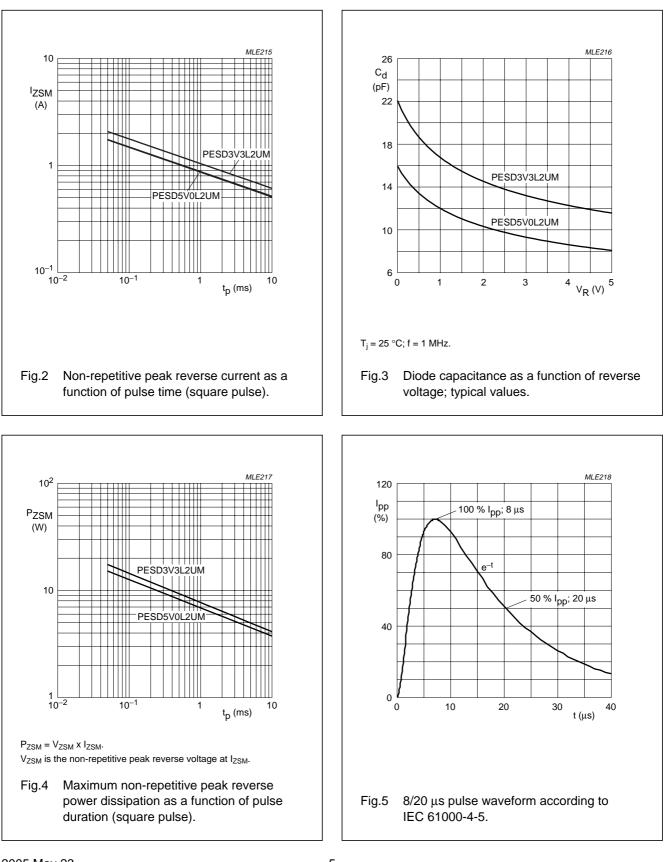
$T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Per diode			I	-1		1
V _F	forward voltage	I _F = 200 mA	-	1	1.2	V
V _{RWM}	reverse stand-off voltage					
	PESD3V3L2UM		_	_	3.3	V
	PESD5V0L2UM		_	_	5	V
I _{RM}	reverse leakage current					
	PESD3V3L2UM	V _R = 3.3 V	-	75	300	nA
	PESD5V0L2UM	V _R = 5 V	-	5	25	nA
V _{(CL)R}	clamping voltage	8/20 μs pulse				
	PESD3V3L2UM	$I_{pp} = 1 \text{ A}$; notes 1 and 2	-	-	8	V
		$I_{pp} = 3 \text{ A}$; notes 1 and 2	-	-	12	V
		$I_{pp} = 1 \text{ A}$; notes 1 and 3	_	_	9	V
		$I_{pp} = 3 \text{ A}$; notes 1 and 3	_	_	13	V
	PESD5V0L2UM	$I_{pp} = 1 \text{ A}$; notes 1 and 2	_	_	10	V
		$I_{pp} = 2.5 \text{ A}$; notes 1 and 2	_	_	13	V
		$I_{pp} = 1 \text{ A}$; notes 1 and 3	_	_	11	V
		$I_{pp} = 2.5 \text{ A}$; notes 1 and 3	-	_	15	V
V _{BR}	breakdown voltage	I _Z = 1 mA				
	PESD3V3L2UM		5.32	5.6	5.88	V
	PESD5V0L2UM		6.46	6.8	7.14	V
Sz	temperature coefficient	I _Z = 1 mA				
	PESD3V3L2UM		-	1.3	-	mV/K
	PESD5V0L2UM		-	2.9	-	mV/K
r _{diff}	differential resistance	I _R = 1 mA				
	PESD3V3L2UM		-	_	200	Ω
	PESD5V0L2UM		-	_	100	Ω
C _d	diode capacitance					
	PESD3V3L2UM	f = 1 MHz; V _R = 0	-	22	28	pF
	f = 1 MHz; V _R = 5		-	12	17	pF
	PESD5V0L2UM	f = 1 MHz; V _R = 0	-	16	19	pF
		f = 1 MHz; V _R = 5	_	8	11	pF

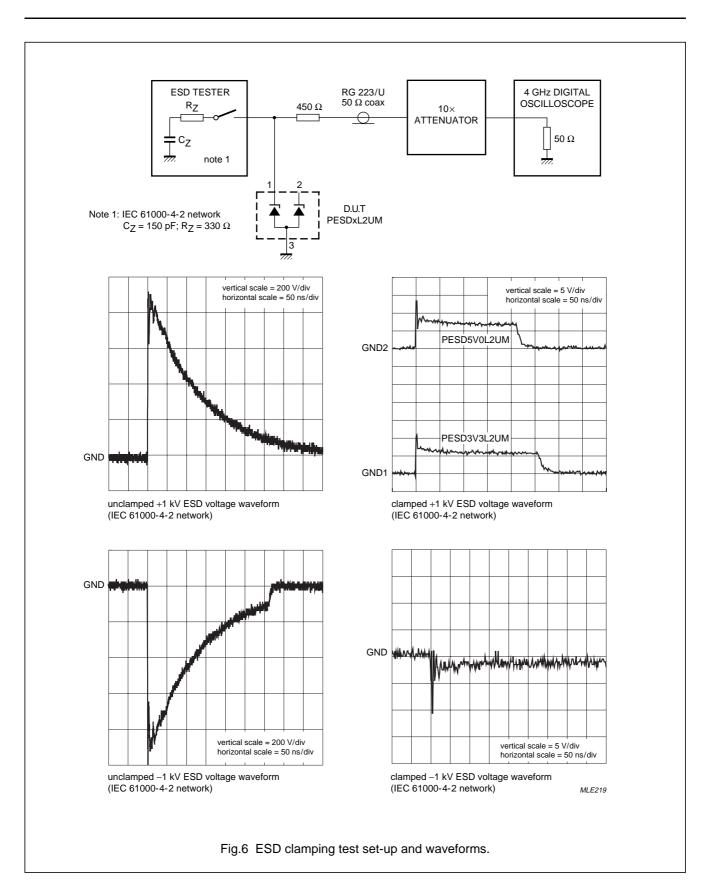
Notes

- 1. Non-repetitive current pulse 8/20 μs exponential decay waveform; see Fig.5.
- 2. Pins 1 and 3 or 2 and 3.
- 3. Pins 1 and 2.

PESDxL2UM series

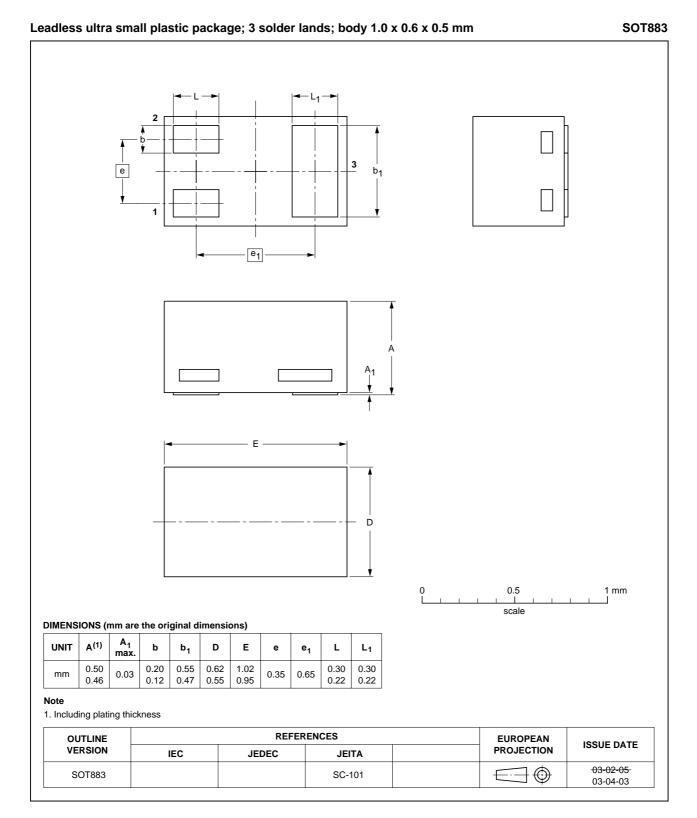






PESDxL2UM series

PACKAGE OUTLINE



PESDxL2UM series

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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